

Formation of Thin Films of Organic–Inorganic Perovskites for High-Efficiency Solar Cells

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Organic–inorganic perovskites are currently one of the hottest topics in photovoltaic (PV) research, with power conversion efficiencies (PCEs) of cells on a laboratory scale already competing with those of established thin-film PV technologies. Most enhancements have been achieved by improving the quality of the perovskite films, suggesting that the optimization of film formation and crystallization is of paramount importance for further advances. Here, we review the various techniques for film formation and the role of the solvents and precursors in the processes. We address the role chloride ions play in film formation of mixed-halide perovskites, which is an outstanding question in the field. We highlight the material properties that are essential for high-efficiency operation of solar cells, and identify how further improved morphologies might be achieved.

1. Introduction

The search for low-cost alternatives to power sources based on fossil fuels has become of paramount importance in light of rising power costs, recent requirements for the reduction of emissions, and in order to enable the electrification of the developing world. Solar photovoltaics (PVs) are potentially suitable alternatives. The International Energy Agency estimates that the total primary energy supply, the sum of all of the world's power supply averaged over the year, will be approximately 20 TW by 2035.^[1] In comparison, the power from the sun intercepted by the earth is around 180 000 TW, meaning that solar energy is a virtually limitless resource. The current PV market is dominated by silicon-based technologies, which are based on high-efficiency mono-

or multi-crystalline solar cells with a record power conversion efficiency (PCE) of incident sunlight to electricity of around 25 %. The price per Watt of solar power from silicon PVs has plummeted in recent years, and it can now provide power at costs close to grid parity in some regions.^[2] Even if

the costs of solar-cell-active materials become negligible, other costs, such as protective casing, wiring, installation, and maintenance, will remain, and therefore the total costs of electricity from solar power could be further reduced most significantly by increasing the PCE. Further price reductions will require a technology that features lower material costs and also higher PCEs.

Organic–inorganic perovskites have the potential to be such a “disruptive” technology. Power conversion efficiencies of PV devices that contain these materials have increased from around 4 % to a certified 20.1 % in the last three years.^[3] Based on their efficiency, they are already rivaling established thin-film technologies, such as those based on cadmium telluride (CdTe) and copper indium gallium selenide (CIGS).^[4] These perovskites show remarkable optical absorptions across a wide range of the solar spectrum, and a sharp optical band edge, which suggests low levels of disorder.^[5] They also exhibit long charge-carrier diffusion lengths ($> 1 \mu\text{m}$) relative to the absorption depth of incident light ($\approx 100 \text{ nm}$),^[6] meaning that almost all photoexcited species in the perovskite are able to reach the interfaces from where the charges are then transported through suitable hole- and electron-transporting layers to the electrodes. Most of the significant improvements in PCE have been a direct result of improvements in the formation of perovskite films,^[3c,7] which

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led to a better film uniformity and larger crystalline domains, thus suggesting that these features are of the utmost importance for achieving high performance.

In this Minireview, we will focus on the materials chemistry aspects of perovskite films. We will present a detailed description of the different methods for the formation of films and the role of the solvent and starting components, clearly highlighting the material properties that are essential for high-efficiency operation of solar cells. We note that there are several other challenges that need to be solved before we will see the deployment of this technology, but those are beyond the focus of the present Minireview and we refer the interested reader to other reports.^[8]

1.1. Organic–Inorganic Perovskites

Perovskites are a family of materials that share a crystal structure with calcium titanate, that is, ABX_3 (Figure 1 a). The predominant three-dimensional hybrid perovskites used in solar cells to date have short-chain organic cations, such as methylammonium (MA; $A = CH_3NH_3^+$), metal cations such

as lead ($B = Pb^{2+}$), and halides ($X = I^-$, Br^- , Cl^- or mixtures). Here, we will focus primarily on $MAPbI_3$ and the mixed-halide analogue, $MAPbI_{3-x}Cl_x$, although we also direct the reader to the growing number of reports on alternative organic cations,^[9] metal cations,^[10] and halides.^[5b,9c,11] The X-ray diffraction (XRD) spectrum of $MAPbI_{3-x}Cl_x$ (Figure 1 b) shows its tetragonal crystal structure at room temperature (160–330 K).^[12]

Two dominant structural concepts have emerged for perovskite solar cells: the planar heterojunction (Figure 1 c), in which the perovskite is a simple flat layer that is sandwiched between n- and p-type contacts, and the mesostructured cell (Figure 1 d), in which the perovskite infiltrates a mesoporous metal oxide scaffold, which is either an n-type TiO_2 layer or an insulating dielectric scaffold, and additionally typically forms a solid absorber layer on top of the scaffold.^[7,13] For the mesostructured cell, the mesoporous metal oxide aids the formation of the perovskite film and its uniformity over a large area and, in the case of the scaffold being n-type TiO_2 , it also assists in the charge extraction in the region near the planar n-type contact. Both concepts (planar and meso) are currently evolving and are likely to eventually



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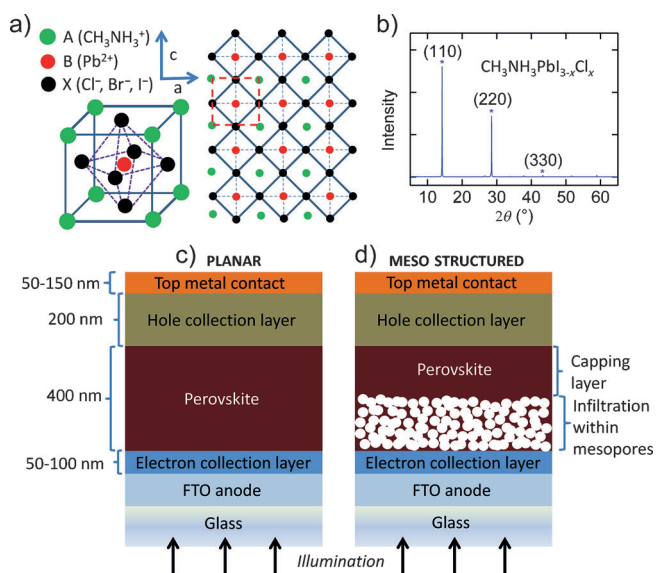


Figure 1. a) Crystal structure of perovskites. b) X-ray diffraction (XRD) spectrum of a $\text{CH}_3\text{NH}_3\text{PbI}_{3-x}\text{Cl}_x$ film prepared by spin-coating of the precursors on a glass substrate and annealing at 100°C .^[3b] c,d) Schematics representing the planar c) heterojunction and d) mesostructured device architectures.

converge in a single architecture. Herein, we will discuss both concepts in the context of perovskite film formation, but we refer the reader to Refs. [8ab] for further details about the architectures. We also note that an “inverted” structure is considered here to be an inverted architecture with respect to that in Figure 1c, that is, in which holes are collected through the bottom electrode.

2. Deposition Methods

A number of methods to fabricate thin films of organic–inorganic perovskites have emerged, each resulting in varying degrees of surface coverage, and crystal and film quality. Most methods are based on the same principle: the combination of an organic component, such as methylammonium iodide (MAI), with an inorganic component, such as PbI_2 or PbCl_2 , to form the perovskite (MAPbI_3 or $\text{MAPbI}_{3-x}\text{Cl}_x$, respectively). In the following sections, we will describe the films resulting from various deposition methods.

2.1. One-Step Deposition

In the simplest formulation, the two precursor salts (metal halide and organic halide) are dissolved in an organic solvent (see Section 3), the mixture is spin-coated onto a substrate, and the perovskite is formed through an annealing process at around 100°C . The first high-performance devices were obtained following this protocol to deposit the mixture on mesoporous n-type TiO_2 or insulating Al_2O_3 scaffold substrates, where the scaffolds were themselves on top of a thin n-type compact TiO_2 layer.^[3b,d] However, spin-coating the mixture directly onto the compact n-type contact, as for

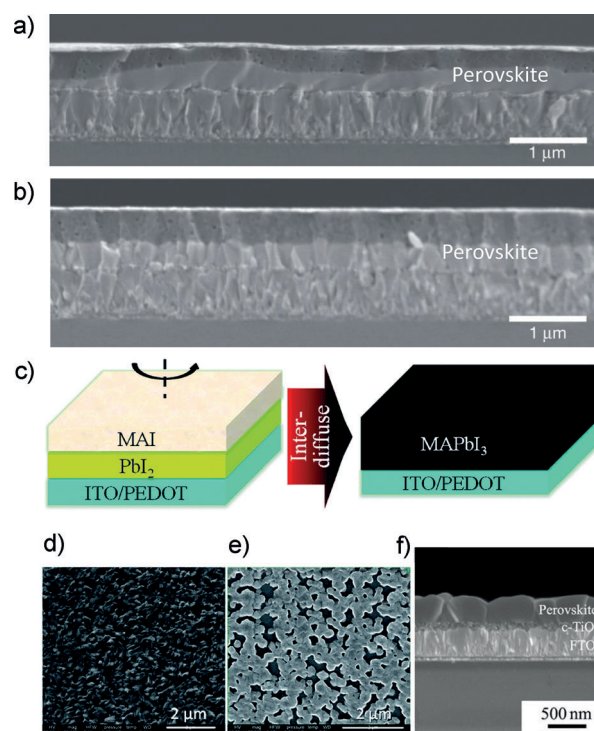


Figure 2. a,b) Cross-sectional SEM images of full devices featuring perovskite films prepared by a) solution processing and b) vapor deposition.^[17] c) Schematic of the interdiffusion method. d,e) Top-view SEM images of the films resulting from d) interdiffusion and e) solution-processing. Reproduced from Ref. [19] with permission from The Royal Society of Chemistry. f) Cross-sectional SEM image of a perovskite film prepared using the vapor-assisted conversion (VASP) method. Reprinted with permission from the American Chemical Society, Ref. [20]. SEM = scanning electron microscope.

planar heterojunction architectures, initially resulted in a dewetting effect,^[14] thus leading to poor surface coverage (Figure 2e).^[13a,15] This in turn resulted in poor device performance as a result of low-resistance shunting paths and low light absorption in the solar cell. The surface coverage and device performance are both highly dependent on the processing conditions. We found that processing in a nitrogen atmosphere, optimizing the spin-coating protocol, and lowering the annealing temperature to 90°C improves coverage ($> 90\%$) and film morphology, with devices reaching a PCE of more than 12% .^[6a,15] Additionally, we have recently shown that a rapid “flash” post-anneal treatment at 130°C promotes the growth of highly uniform micrometer-sized textured perovskite domains (PCE of 13.5%), while the standard annealing conditions (100°C) result in polycrystalline perovskite domains of $100\text{--}1000\text{ nm}$ in size.^[16]

Despite improved coverage, spin-coated films generally show an undulating variation in thickness across the substrates (Figure 2a), which is not ideal for reproducible and optimized device performance.^[17] Moving away from solution-based spin-coating techniques, we have shown that highly uniform $\text{MAPbI}_{3-x}\text{Cl}_x$ films with nearly 100% surface coverage can be obtained using a dual-source co-evaporation^[18] of MAI and PbCl_2 (Figure 2b), followed by an annealing step at 100°C .^[17] We achieved a device PCE of

15.4 % using this method, again suggesting that uniform films with high coverage are essential for high performance. We note that the perovskite crystals obtained by the vapor-deposition technique are a few hundred nanometers in size, and thus smaller than the micrometer-sized platelets obtained from spin-coating. Furthermore, evaporation has the added advantage of being more compatible with multi-junction architectures, for example to process perovskites as top cells for existing silicon technologies, or multiple perovskite junctions.^[8a,17]

Recently, Barrows et al. demonstrated the use of ultrasonic spray-coating under ambient conditions as a means to fabricate planar heterojunction MAPbI_{3-x}Cl_x solar cells.^[21] By optimizing the temperature of the substrate during spray-coating and the post-annealing temperature, they were able to achieve reasonable surface coverage (> 85 %) with micrometer-sized platelets, and a device PCE of 11.1 %. This result is promising for low-cost, large-area manufacturing.

2.2. Two-Step Deposition

Additional control over the morphology can be achieved by sequentially depositing the two precursors.^[22] In the “sequential-deposition” method, Burschka et al. first infiltrated a mesoporous TiO₂ film with a solution containing PbI₂ and subsequently converted the film to MAPbI₃ perovskite by exposing it to a solution of MAI.^[13c] The conversion occurred at room temperature within seconds. Devices fabricated using the mesostructured TiO₂ architectures achieved a PCE of 15.3 %. Without a perovskite capping layer, in which all the perovskite was entirely within the mesoporous TiO₂, efficiencies up to 13 % were achieved.^[23] We note that the mesoporous scaffold limited the size of the perovskite crystals to around 20 nm.

This method to convert PbI₂ to a perovskite has also been demonstrated with solid films of PbI₂ for use in planar heterojunction device architectures. Liu and Kelly reported the conversion of thin spin-coated films of PbI₂ to MAPbI₃ by immersion of PbI₂ in solutions of MAI.^[24] The absence of the mesoporous layer allowed the unconstrained growth of the perovskite crystallites (~100–1000 nm) and, by optimizing the MAI concentration, solution temperature, and dipping time, a device PCE of 15.7 % was achieved. Similar high-performance devices were demonstrated by Docampo et al. by immersing the PbI₂ films in MACl instead of MAI.^[25] Yongzhen et al. showed that the crystallization of the initial PbI₂ layer can be retarded by the use of dimethylsulfoxide (DMSO) as the solvent instead of *N,N*-dimethylformamide (DMF), which is typically used, resulting in more controlled particle sizes, more complete conversion, and increased reproducibility of film quality.^[26]

Aside from conversions in solution, Yang and co-workers demonstrated the vapor-assisted solution processing (VASP) conversion of the PbI₂ to MAPbI₃ by exposing the film to an MAI vapor^[20] (as opposed to MAI in solution). The method produced films with well-defined grain structures with crystallites on the micrometer scale, complete surface coverage, and low surface roughness (Figure 2 f). The authors

demonstrated a device PCE of 12.1 %. The advantage of vapor-based conversion over solution-based methods is that dissolution of the already converted perovskite is minimized, generally resulting in smoother films with less faceted crystals.

Xiao et al. recently demonstrated a method in which the precursor materials were sequentially spin-coated as bilayer stacks and the conversion of the perovskite was achieved by “interdiffusion” of the layers, as shown in Figure 2 c.^[19] The resulting films showed excellent surface coverage and low roughness (Figure 2 d). The highest PCE (15.4 %) was obtained in an inverted solar-cell configuration with a thickness of PbI₂/MAI of 140/190 nm, with annealing at 100 °C for 2 h. Chen et al. demonstrated further improvements in smoothness using the same method but with sequential thermal evaporation of the precursor layers (PbCl₂ and MAI).^[27] Park and co-workers used this two-step interdiffusion method with a thin mesoporous (~100 nm) TiO₂ layer; the resulting capping layer of perovskite comprises “cuboid” crystals whose size is strongly dependent on the MAI concentration.^[28] They demonstrated a device with a PCE of 17.0 %.

3. Role of the Solvent

The control of the crystallization and thus the kinetics of film formation during deposition and annealing are the key to the optimization of device performance. Optimal film morphology can only be achieved by successfully manipulating the nucleation and growth of the perovskite, for which “solvent-engineering” is a very effective technique.^[7]

3.1. Dissolving Precursors

For a thin film, high precursor concentrations are required in order to obtain a continuous, dense layer with suitable optical density (typically >0.5 m). Suitable solvents for perovskite precursors appear to be limited to highly polar aprotic solvents, such as DMF, DMSO, γ -butyrolactone (GBL), acetonitrile etc. In the first reports on perovskite solar cells, the precursors were mixed in GBL for PbI₂^[3d] or DMF for the more difficult to dissolve PbCl₂.^[3b] DMF can also be replaced by solvents with a similar (e.g. *N*-methylpyrrolidone, NMP) or even higher (e.g. DMSO) dielectric constant, although the surface coverage is quite poor, likely because the employed solvents evaporate more slowly.^[15]

A typical crystallization trick is the use of a mixed solvent. Liang et al. added 1,8-diiodooctane (DIO) to DMF, which resulted in the formation of films with more uniform crystals and more ordered growth directions.^[29] These features, along with the enhanced solubility of PbCl₂ (as a result of chelation of Pb²⁺ with DIO), which led to an improved surface coverage, resulted in inverted solar cells with enhanced PCEs (from 9.0 up to 11.8 % with the addition of only 1 % DIO). Likewise, other groups employed mixtures of GBL in DMF (3 vol %), which mainly influenced the film coverage rather than the crystalline structure of the material, thus leading to improved photovoltaic performance in comparison with neat GBL or DMF solutions of MAPbI₃ perovskite (17 % net

increase in PCE).^[8d] There is also evidence to suggest that ageing the precursor solution before casting could be beneficial.^[30]

3.2. Solvent Engineering

A key breakthrough in improving the efficiencies of perovskite solar cells came from the group of Sang Il Seok, who employed a “solvent engineering” technique (Figure 3a) to deposit $\text{MAPb}(\text{I}_{1-x}\text{Br}_x)_3$ onto thin mesoporous TiO_2 scaffolds.^[7] They used a mixture of GBL and DMSO (7:3 v/v) as a co-solvent for the precursors, where the more volatile solvent (i.e. GBL) evaporates during spin-coating. Subsequently, toluene was deposited on the film during spin-coating. The precise mechanism is not yet clear, but presumably the “nonsolvent” for the perovskite constituents causes the salts to rapidly precipitate out of solution into a smooth precrystallized film, potentially consisting of a MAI-PbI_2 -DMSO intermediate phase. As a final step, annealing at 100°C for 10 min led to the formation of the MAPbI_3 perovskite by driving out the entrapped (or coordinated) DMSO. This procedure resulted in compact and uniform capping layers with grain sizes in the range of 100 to 500 nm with a 100% surface coverage of the substrate (Figure 3b). These features resulted in the fabrication of solar cells with certified efficiencies of 16.2%, and we suspect that a similar technique but further advanced (including the use of a blend

of methylammonium lead bromide and formamidinium lead iodide perovskites)^[49] has resulted in certified efficiencies of 20.1%.^[3e]

Likewise, Spiccia and co-workers fabricated planar heterojunction solar cells with an average PCE of 13.9% (with a maximum PCE at 16.2%), accompanied by high reproducibility (mean deviation of 0.7%), by employing a fast deposition–crystallization (FDC) procedure,^[31] which is almost identical to that used by Il Seok, apart from chlorobenzene being employed as the nonsolvent. As Spiccia et al. did not employ DMSO, the perovskite film instantly crystallized when the perovskite constituents precipitated out, evidenced by the instant darkening of the film. The obtained crystalline grains spanned the thickness of the film (approximately micrometer size), being large and free of boundaries in the perpendicular direction, thus allowing for full coverage of the substrate. Our experience is that the method of Spiccia et al. produces films with an impressive mirror-like reflection.

In a different approach, Xiao et al. introduced vapors of DMF during annealing in order to provide a solvent-swollen environment so that the precursor ions could more effectively diffuse compared with all-solid-state thermal annealing.^[32] The authors prepared films using two-step deposition and further treated (or not) the perovskite with vapors of DMF during annealing at 100°C for 1 hour. Indeed, the observed differences were spectacular; the grain size of the solvent-annealed films grew much faster than the thermally annealed films. This technique led to solvent-annealed films with

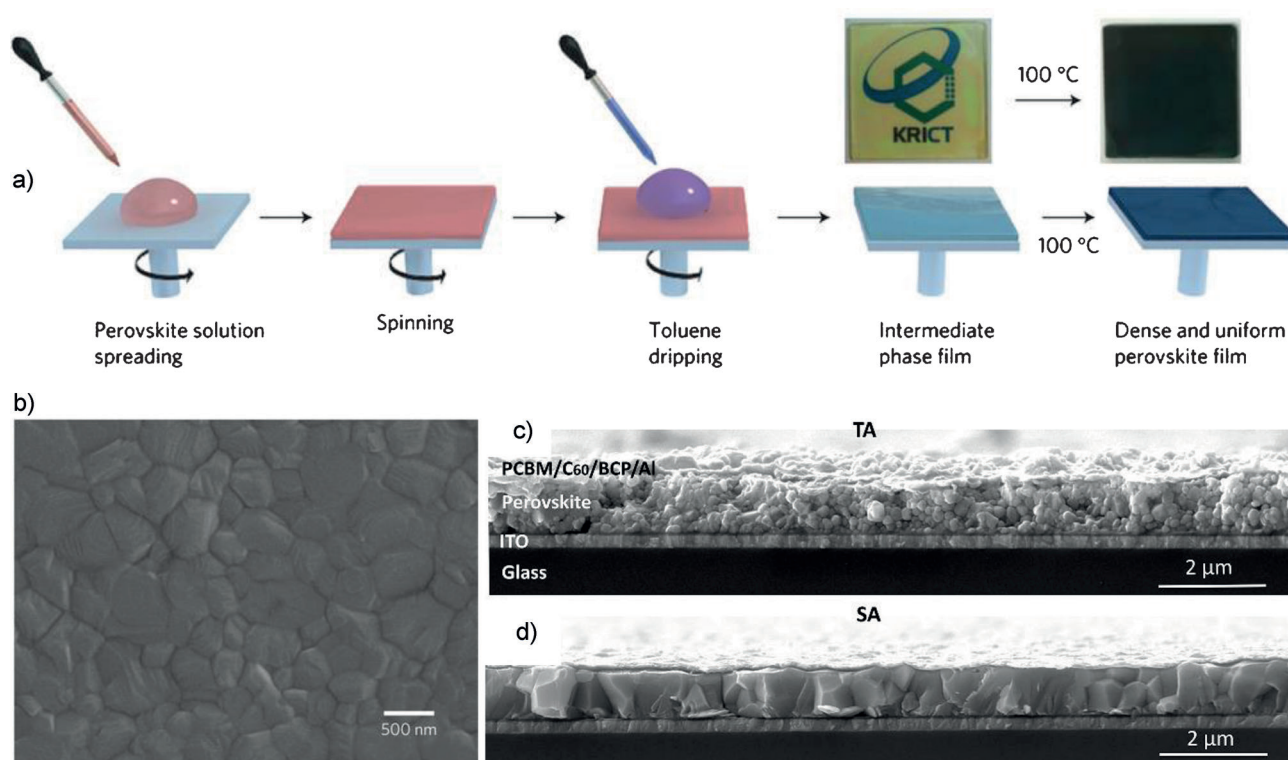


Figure 3. a) Schematic of the solvent-engineering technique and b) top-view SEM image of the resulting $\text{MAPb}(\text{I}_{1-x}\text{Br}_x)_3$ perovskite film. Reprinted with permission from Macmillan Publishers Ltd: Nature Materials,^[7] copyright 2014. c,d) Cross-sectional SEM images of inverted planar heterojunction solar cells with the perovskite produced by c) standard thermal annealing (TA) and d) solvent annealing (SA). Reprinted from Ref. [32].

average grain sizes that were consistently larger and more comparable to the film thickness (Figure 3d) than those of the thermally-annealed films (Figure 3c). Finally, this method resulted in 630 nm thick solvent-annealed inverted solar cells with efficiencies of 15.6%, which is substantially higher than those attained by the thermally annealed devices (9.9%). A similar approach was employed by C.-H. Chiang et al., who treated both PC₇₁BM and the perovskite with solvent vapors by simply covering the perovskite/PC₇₁BM film with a Petri dish with a solvent atmosphere for 24 h. Again, the efficiencies of the inverted solar cells were excellent, reaching up to 16.3%.^[33]

Recently, Yang and co-workers fabricated planar heterojunction solar cells with MAPbI_{3-x}Cl_x perovskite, produced using an enhanced “reconstruction process” under controlled-humidity conditions (30% relative humidity)^[36].^[34] The formation of these films progressed via an intermediate MAPbCl₃ phase, which was later consumed. The films were also of higher quality than those produced under dry conditions, as evidenced by longer carrier lifetimes, which suggest suppressed recombination. The positive influence of moisture during the crystallization process on carrier lifetimes has recently also been reported elsewhere.^[35] Yang et al. speculate that water aids the formation by partially dissolving reactant species and accelerating mass transport, which is essentially a form of solvent-vapor annealing. Combined with improved interfaces, they reported a PCE of 19.3%. We note that exposure to moisture after film formation is highly detrimental to the perovskite and will lead to degradation.^[36]

4. The Role of the Precursors

4.1. The Role of Chloride Ions in Film Formation

Lee et al. demonstrated the fabrication of perovskites using PbCl₂ and MAI in the precursor solution,^[3b] and termed the product MAPbI_{3-x}Cl_x.^[13a] In the precursor solution, MAI and PbCl₂ were present in a nonstoichiometric ratio of 3:1. Topics of debate in recent articles^[8c,37] included whether any chloride ions remain in the perovskite crystal lattice, how many chloride ions remain in the films, and what the role of chloride ions is in film formation. It was even argued that a formula such as MAPbI_{3-x}Cl_x should be avoided, as no Cl⁻ has yet been detected in the crystal lattice.^[8c,38]

Recent experimental and theoretical investigations highlighted the crucial role of Cl⁻ in MAPbI_{3-x}Cl_x perovskite solar cells.^[3b,6a,25] Measurements have shown that the perovskite films that were fabricated using the PbCl₂/MAI precursors to form MAPbI_{3-x}Cl_x have significantly longer charge-carrier diffusion lengths (>1 μm) than their triiodide (MAPbI₃) counterparts (≈100 nm).^[6a,b,d] As the observed band gap remains more or less unchanged for the triiodide and “mixed-halide” films, we expect that, if any, there is only a small amount of Cl⁻ present in the lattice of the final absorber material. From experimental and theoretical work, Colella et al. proposed that, at best, only 2–3% of the Cl⁻ ions can be included in the lattice of a mixed-halide-based absorber material.^[39] From angle-resolved X-ray photoelectron spec-

troscopy (AR-XPS) measurements, the authors suggest that the Cl⁻ ions are preferentially positioned at the interface of TiO₂ and perovskite.^[40] Williams et al. used a thermal analysis coupled with Fourier transform infrared (FTIR) spectroscopy to show that films prepared from the mixed-halide precursor solution (i.e. PbCl₂ and MAI in DMF) contain some Cl⁻ ions and that the thermal properties are different from those of the stoichiometric MAPbI₃ film.^[41] D’Innocenzo demonstrated that the tetragonal to orthorhombic phase-transition temperature for the triiodide and mixed-halide perovskite differed by 30 K.^[12c] In light of the above findings, we suggest that we should use the formula MAPbI_{3-x}Cl_x for the films prepared from the mixed-halide solutions. However, the quantitative determination of the ratio of Cl⁻ to I⁻ and their optimal ratio for solar-cell applications is yet to be determined. In addition, whether Cl⁻ is predominantly present as a substituent for I⁻, as an interstitial, or at the surface of the crystal, remains unclear. Initial attempts to detect Cl⁻ by techniques such as energy-dispersive X-ray spectroscopy (EDX), electron-energy-loss spectroscopy (EELS) or surface-sensitive X-ray photoelectron spectroscopy (XPS) failed to detect the presence of Cl⁻, as the amount was beyond the detectable limit of the technique and/or the techniques probed the bulk sample.^[25,38,40]

Though it is becoming clear that Cl⁻ ions are present in small amounts at the interface of TiO₂ and perovskite, it is not yet clear what happens to the remaining Cl⁻ ions that are included in the precursor solution, and how Cl⁻ ions affect the film formation. Through a combination of thermal, structural, and chemical characterization methods, Yu et al. investigated the role of Cl⁻ ions in the formation of MAPbI_{3-x}Cl_x films.^[42] They found that most of the Cl⁻ ions leave the matrix as gaseous MACl during the annealing procedure, while the formation of the mixed-halide phase occurs via an intermediate organic–inorganic mixed-halide phase. The excess of CH₃NH₃⁺ that is used in the precursor solution is essential for the formation of large crystal domains, as it slows down the crystal formation process. The presence of Cl⁻ ions facilitates the release of excess CH₃NH₃⁺ ions, whereas CH₃NH₃I is not sufficiently volatile in the thin film.

Furthermore, recent studies have shown that the presence of Cl⁻ ions in the precursor solution lead to nucleation centers that assist perovskite growth.^[30,43] Williams et al. showed that the presence of Cl⁻ ions gives rise to a fused CH₃NH₃PbCl₃ template phase that seeds and directs the growth of larger crystalline perovskite domains than the triiodide analogue, along with better surface coverage.^[30] Tidhar et al. showed that the insoluble PbCl₂ forms nanocrystals that act as heterogeneous nucleation centers for the formation of perovskite crystals in solution.^[43] We note here that a similar effect was seen in the methylammonium lead bromide systems, where the inclusion of a small quantity of Cl⁻ also improved solar-cell performance when compared to the tribromide counterpart as a result of the better morphology.^[11a] In addition to the effect on morphology, Cl⁻ ions may also induce band bending at the TiO₂ interfaces that improves charge collection efficiency.^[40]

4.2. The Role of the Anions: Alternative Precursors

Related to the role of chloride ions, we recently systematically studied the role of the precursor anions in the Pb source in the crystallization of perovskite thin films.^[44] We found that the anions determine the kinetics of perovskite crystal growth, which in turn affects the film morphology and device performance. As the perovskite precursor solution, we employed the Pb salts PbCl_2 , PbI_2 , and lead acetate (PbAc_2), each dissolved in DMF with a three-fold excess of MAI. The precursor solutions were then spin-coated and the substrates were annealed. All processing routes led to the formation of a material that is predominantly MAPbI_3 , but with considerably different properties of the thin films. The perovskite films prepared from PbCl_2 (Figure 4a) and PbI_2 (Figure 4b)

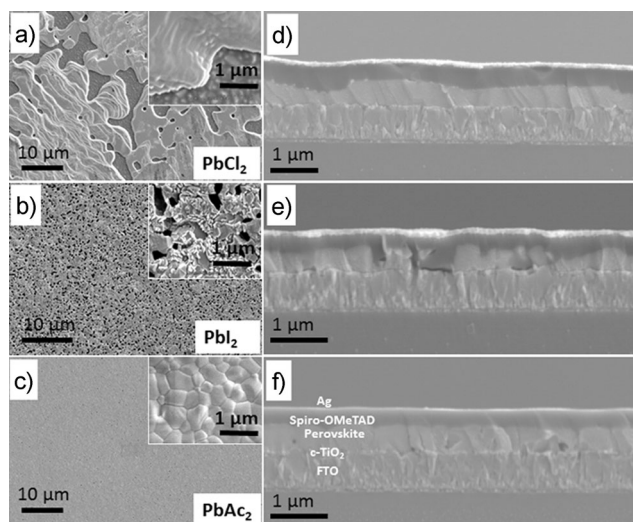


Figure 4. SEM images of perovskite films deposited on $\text{FTO}/\text{c-TiO}_2$ substrates from the three different Pb sources: a) PbCl_2 , b) PbI_2 , and c) PbAc_2 , (insets show images with higher resolution); cross-sections of full devices with the perovskite derived from d) PbCl_2 , e) PbI_2 , and f) PbAc_2 . Reprinted with permission from Macmillan Publishers Ltd: Nature Communications,^[44] copyright 2015.

are noncontinuous, with pinholes of different lengths and no clear grain boundaries of the crystals. By contrast, the perovskite films derived from PbAc_2 (Figure 4c) exhibit a considerably different morphology, attaining almost full coverage on the substrates with crystal grain sizes in the range 100–1000 nm (Figure 4c, inset). In addition, the cross-sectional SEM images clearly show that the perovskite films obtained through the PbAc_2 route are much smoother (Figure 4f) than the films prepared from PbCl_2 (Figure 4d) and PbI_2 (Figure 4e). We quantified this smoothness using atomic force microscopy (AFM), which showed that the root-mean-square roughness of the perovskite films prepared from PbCl_2 , PbI_2 , and PbAc_2 is 62.4, 52.2 and 12.3 nm, respectively. Remarkably, the films prepared from PbAc_2 are smoother than those of the dual-source vapor-deposited films prepared from PbCl_2 (16.2 nm), which had until now resulted in much smoother and more continuous films than solution coating. Sargent and co-workers have also observed similar results

when comparing PbI_2 and PbAc_2 , consistent with our findings.^[45]

In order to achieve the best device performance, the perovskite films prepared from PbCl_2 and PbI_2 needed to be annealed for 2 h at 100°C and 40 min at 150°C, respectively. However, the optimized annealing time was much shorter for the films prepared from PbAc_2 (5 min at 100°C), which is consistent with the much more facile removal of excess MAAC during crystallization compared with the removal of MAI or MAI. The average PCE of complete solar cells constructed with perovskites that were prepared with optimized annealing times from PbCl_2 , PbI_2 , and PbAc_2 were 12.0, 9.3, and 14.0%, respectively. Therefore, by using PbAc_2 as the Pb source, we have achieved a much faster and more uniform crystallization compared with the other two routes, and thus improved device performance. The PbAc_2 route offers the possibility of employing precursor salts that do not only contain the eventual perovskite components. This implies that a much broader range of precursors can be investigated, with the “spectator ions” chosen for properties that can enhance or control processing, thin-film formation, and crystallization.

5. Summary and Outlook

Methods for the formation of organic–inorganic perovskite films have evolved significantly since the first reports of 2 nm sized nanoparticles coated upon a mesoporous TiO_2 electrode in 2009.^[3a] The quality of the films resulting from simple solution processing, in which the precursors are dissolved in a single organic solvent^[3b,d], has been surpassed by a variety of optimizations and alternative methods, such as two-step conversions. For high-performance planar heterojunction solar cells, it is essential to have nearly complete surface coverage to prevent both low-resistance shunting paths between the n- and p-type contacts, as well as low light absorption in the solar cell. This goal can be achieved using optimized spin-coating and annealing,^[15] co-evaporation,^[17] and two-step methods including solvent^[13c,24] and vapor^[20] conversions, interdiffusion,^[19,28] and post treatments, such as solvent-vapor annealing.^[3c,32,33] Aside from continuous films, large crystalline domains are desirable and can also be achieved using many of these methods. Our interpretation of the results from the various methods is that the induction of fast crystallization promotes near perfect surface coverage, while slower crystallization promotes the growth of larger crystals, but with generally lower coverage. The highest quality films (and highest published certified PCE) have been obtained using “solvent engineering” techniques,^[7,31,49] whereby crystallization is optimized by exploiting relative volatilities and binding abilities of various solvents and reactants. This technique appears to be a very promising route for producing high-quality crystalline films.

The presence of chloride ions in the “mixed-halide” perovskite films, formed from MAI/ PbCl_2 precursors, has been the subject of debate for some time.^[3b,8c] While it is likely that chloride ions are only present in the lattice in tiny amounts (beyond the detection limit of many techniques), physical differences have been observed between that prod-

uct and MAPbI_3 ,^[40] justifying the mixed-halide formula of $\text{MAPbI}_{3-x}\text{Cl}_x$ (with x being small and to be defined, and no doubt varying between preparation routes). It is becoming clear that the excess CH_3NH_3^+ and the presence of Cl^- primarily assists in film formation, leading to planar films with generally superior properties compared to their triiodide counterparts. This role in film formation is not unique to chloride ions; we have shown that the acetate anion in the precursor can also lead to ultrasmooth films of very high quality,^[44] but other spectator anions might lead to even more improved film formation.

Perovskites have been shown to have low intergrain potential barriers.^[46] Nevertheless, several recent reports have shown that there is a significant subgap trap density that plays a crucial role in recombination.^[6b,45,47] The origin of the traps is as yet unclear, but they could arise from vacancies through the bulk or on crystal surfaces. Suitable surface treatments can passivate these sites to a certain extent, but not entirely.^[48] Aside from the further optimization of film morphology, the prevention of the formation of these trap states, or at least minimizing their influence, will be key to future advances in device performances. It is our understanding that the continued increase in the domain size of crystals and the uniformity of thin-film deposition will be the main factors that will increase the performance of perovskite solar cells over the next few years.

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